#### 查询SN54F241供应商

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Plastic and Ceramic DIPs

#### description

These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the 'F240 and 'F244, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical  $\overline{OE}$  (active-low output-enable) inputs, and complementary OE and  $\overline{OE}$  inputs.

The SN54F241 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74F241 is characterized for operation from 0°C to 70°C.

SN54F241 J PACKAGE SN74F241 DW OR N PACKAGE (TOP VIEW)									
1 <u>0</u> [	1	20	] V <sub>CC</sub>						
1A1	2	19	20E						
2Y4	3	18	1Y1						
1A2 [	4	17	] 2A4						
2Y3 [	5	16	] 1Y2						
1A3 [	6	15	] 2A3						
2Y2 [	7	14	] 1Y3						
1A4 [	8	13	] 2A2						
2Y1 🛙	٥	12	1174						

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OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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#### SN54F241 ... FK PACKAGE (TOP VIEW)

11

2A1

GND [

10

	2Y4 1A1	20 C C C	
1A2 2Y3 1A3 2Y2 1A4	3 2 1 4 5 6 7 8	20 19 18 17 16 15 14 1 12 13	1Y1 2A4 1Y2 2A3 1Y3
	2Y1 GND	1Y4 2A2	50.0

	FUNCTION TABLES									
1	INP	JTS	OUTPUT							
	10E	1A	1Y							
	Н	Х	Z							
	L	Н	Н							
	L	L	L							

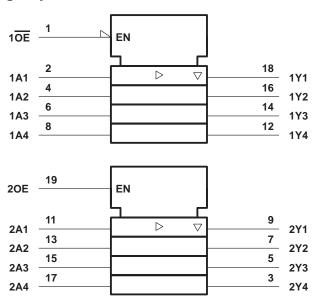
INPU	JTS	OUTPUT
20E	2A	2Y
Н	Н	Н
Н	L	L
L	Х	Z





# SN54F241, SN74F241 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SDFS090 – MARCH 1987 – REVISED OCTOBER 1993

# logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

#### logic diagram (positive logic) 1<mark>0E</mark> 18 2 1Y1 1A1 16 1Y2 1A2 14 6 1Y3 1A3 12 8 1Y4 1A4 19 20E 9 11 2A1 2Y1 7 13 2Y2 2A2 5 15 2Y3 2A3

17

2A4

3

2Y4

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage range, V <sub>CC</sub>		0.5 V to 7 V
Input voltage range, VI (see Note 1) .		–1.2 V to 7 V
Input current range		
Voltage range applied to any output in	the disabled or power-off state .	−0.5 V to 5.5 V
Voltage range applied to any output in	•	
Current into any output in the low state		
<i>y</i> 1		128 mA
Operating free-air temperature range:		
		0°C to 70°C
Storage temperature range		

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input voltage ratings may be exceeded provided the input current ratings are observed.



# SN54F241, SN74F241 **OCTAL BUFFERS/DRIVERS** WITH 3-STATE OUTPUTS SDFS090 – MARCH 1987 – REVISED OCTOBER 1993

### recommended operating conditions

		SN54F241			SN74F241			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
$V_{IL}$	Low-level input voltage			0.8			0.8	V
Iк	Input clamp current			-18			-18	mA
ЮН	High-level output current	– 12				- 15	mA	
IOL	Low-level output current	48				64	mA	
TA	Operating free-air temperature	-55		125	0		70	°C

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEO	TEST CONDITIONS		N54F24	1	SN74F241				
PARAMETER	AMETER		MIN	түр†	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK	V <sub>CC</sub> = 4.5 V,	lj = -18 mA			-1.2			-1.2	V	
		I <sub>OH</sub> = – 3 mA	2.4	3.3		2.4	3.3			
Vou	$V_{CC} = 4.5 V$	I <sub>OH</sub> = - 12 mA	2	3.2					V	
VOH	JH	I <sub>OH</sub> = – 15 mA				2	3.1			
	V <sub>CC</sub> = 4.75 V,	I <sub>OH</sub> = – 3 mA				2.7				
Voi	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA		0.38	0.55				v	
VOL	VCC = 4.5 V	I <sub>OL</sub> = 64 mA					0.42	0.55		
IOZH	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			50			50	μΑ	
IOZL	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.5 V			-50			-50	μΑ	
Ц	V <sub>CC</sub> = 5.5 V,	$V_{I} = 7 V$			0.1			0.1	mA	
Iн	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V			20			20	μΑ	
OE or C	$V_{CC} = 5.5 V,$	V <sub>1</sub> = 0.5 V			- 1			- 1	mA	
I <sub>IL</sub> Any A	VCC = 3.5 V,	V = 0.5 V			- 1.6			- 1.6	IIIA	
los‡	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0$	-100		-225	-100		-225	mA	
		Outputs high		40	60		40	60		
ICC	$V_{CC} = 5.5 V$	Outputs low		60	90		60	90	mA	
		Outputs disabled		60	90		60	90		

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.
<sup>‡</sup> Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.



# switching characteristics (see Note 2)

	-	TO (OUTPUT)	CI RI	CC = 5 V _ = 50 pl _ = 500 s _ = 25°C	<b>F,</b> Ω,	CL RL	= 50 pF = 500 Ω		V,	UNIT	
			′F241		SN54F241		SN74F241				
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
<sup>t</sup> PLH	Any A	v	1.7	3.6	5.2	1.2	6.5	1.7	6.2	ns	
<sup>t</sup> PHL		Ŷ	1.7	3.6	5.2	1.2	7	1.7	6.5	115	
<sup>t</sup> PZH	OE or OE	v	1.2	3.9	5.7	1.2	7	1.2	6.7		
<sup>t</sup> PZL		Ŷ	1.2	5	7	1.2	8.5	1.2	8	ns	
<sup>t</sup> PHZ	OE or OE		V	1.2	4.1	6	1.2	7	1.2	7	ns
<sup>t</sup> PLZ	OL UI OL		1.2	4.1	6	1.2	7.5	1.2	7	115	

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. NOTE 2: Load circuits and waveforms are shown in Section 1.



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